DATASHEET

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER AC INPUT PHOTOCOUPLER H11AAX Series



Features

- H11AAX series: H11AA1, H11AA2, H11AA3, H11AA4
- · High isolation voltage between input and output
- Viso = 5000 Vrms
- Creepage distance >7.62 mm
- Compact dual-in-line package
- The product itself will remain within RoHS compliant version
- Compliance with EU REACH
- UL and cUL approved(No. E214129)
- VDE approved (No.132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

Description

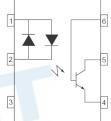
The H11AAX series of devices each consist of two infrared emitting diode, connected in inverse parallel, optically coupled to a phototransistor detector.

They are packaged in a 6-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- AC line monitor
- Unknown polarity DC sensor
- Telephone line interface

Schematic



Pin Configuration

1. Anode / Cathode

- 2. Cathode / Anode
- 3. No Connection
- 4. Emitter
- 5. Collector
- 6. Base

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Absolute Maximum Ratings (Ta=25℃)

	Parameter	Symbol	Rating	Unit
	Forward current	١ _F	60	mA
loout	Peak forward current (t = 10µs)	I _{FM}	1	А
Input	Power dissipation (TA = 25°C)	D	120	mW
	Derating factor (above 90°C)	P _D —	3.8	mW/°C
	Power dissipation (T _A = 25°C) No derating up to 100°C	P _C	150	mW
Output	Collector-Emitter voltage	V _{CEO}	80	V
	Collector-Base voltage	V _{CBO}	80	V
	Emitter-Collector voltage	V _{ECO}	7	V
Total Powe	r Dissipation	P _{TOT}	200	mW
Isolation Vo	oltage* ¹	V _{ISO}	5000	V rms
Operating Temperature		T _{OPR}	-55 to 100	°C
Storage Te	mperature	T _{STG}	-55 to 125	°C
Soldering 7	Femperature* ²	T _{SOL}	260	°C

Notes

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 & 3 are shorted together, and pins 4, 5 & 6 are shorted together. *2 For 10 seconds

Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input							
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Forward Voltage	V _F	-	1.2	1.5	V	$I_F = \pm 10 \text{mA}$	
Input capacitance	C _{in}	-	80	-	pF	V = 0, f = 1MHz	
Output							
Parameter	Symbol	Min	Тур.	Max.	Unit	Condition	
Collector-Emitter dark current	I _{CEO}	-	-	50	nA	$V_{CE} = 10V, I_F = 0mA$	
Collector-Emitter breakdown voltage	BV_{CEO}	80	-	-	V	I _C = 1mA	
Collector-Base breakdown voltage	BV_{CBO}	80	-	-	V	$I_{\rm C} = 0.1 {\rm mA}$	
Emitter-Collector breakdown voltage	BV _{ECO}	7	-	-	V	I _E = 0.1mA	
Collector-Emitter capacitance	C_{CE}	-	10	-	pF	VCE = 0V, f = 1MHz	
Transfer Characteristics Parameter	Symbol	Min	Тур.	Max.	Unit	Condition	
H11AA1		20	-	-			
Current H11AA2	-	20 10	-	-			
	- CTR		-	-	%	I _F = ±10mA ,V _{CE} = 10V	
Current H11AA2 Transfer	- CTR	10		-	%	$I_{F} = \pm 10 \text{mA}$, $V_{CE} = 10 \text{V}$	
Current H11AA2 Transfer ratio H11AA3	- - CTR -	10 50	-	-	%	$I_F = \pm 10 \text{mA}$, $V_{CE} = 10 \text{V}$ $I_F = \pm 10 \text{mA}$, $V_{CE} = 10 \text{V}$	
Current Transfer ratio H11AA3 H11AA4	- CTR - V _{CE(sat)}	10 50 100	-	-	% 		
Current Transfer ratio H11AA2 H11AA3 H11AA4 CTR Symmetry Collector-emitter	-	10 50 100	-	- 2.0		$I_F = \pm 10 \text{mA}$, $V_{CE} = 10 \text{V}$	
Current Transfer ratio H11AA2 H11AA3 H11AA4 CTR Symmetry Collector-emitter saturation voltage	- V _{CE(sat)}	10 50 100 0.5 -	-	- - 2.0 0.4	V	$I_F = \pm 10 \text{mA}$, $V_{CE} = 10 \text{V}$ $I_F = \pm 10 \text{mA}$, $I_C = 0.5 \text{mA}$ $V_{IO} = 500 \text{Vdc}$,	
Current Transfer ratioH11AA2H11AA3H11AA4CTR SymmetryCollector-emitter saturation voltageIsolation resistance	V _{CE(sat)} R _{IO}	10 50 100 0.5 - 10 ¹¹		- - 2.0 0.4	VΩ	$I_F = \pm 10 \text{mA}$, $V_{CE} = 10 \text{V}$ $I_F = \pm 10 \text{mA}$, $I_C = 0.5 \text{mA}$ $V_{IO} = 500 \text{Vdc}$, $40 \sim 60\%$ R.H.	
Current Transfer ratioH11AA2H11AA3H11AA4CTR SymmetryCollector-emitter saturation voltageIsolation resistanceInput-output capacitance	V _{CE(sat)} R _{IO} C _{IO}	10 50 100 0.5 - 10 ¹¹ -	- - - - - 0.7	- 2.0 0.4 -	V Ω pF	$I_{F} = \pm 10mA, V_{CE} = 10V$ $I_{F} = \pm 10mA, I_{C} = 0.5mA$ $V_{IO} = 500Vdc,$ $40 \sim 60\% \text{ R.H.}$ $V_{IO} = 0, f = 1MHz$ $V_{CC} = 10V,$	
Current Transfer ratioH11AA2H11AA3H11AA4CTR SymmetryCollector-emitter saturation voltageIsolation resistanceInput-output capacitanceTurn-on time	V _{CE(sat)} R _{IO} C _{IO} T _{on}	10 50 100 0.5 - 10 ¹¹ - -	- - - - - 0.7 -	- 2.0 0.4 - - 10	VΩ	$I_{F} = \pm 10mA , V_{CE} = 10V$ $I_{F} = \pm 10mA , I_{C} = 0.5mA$ $V_{IO} = 500VdC, $ $40 \sim 60\% R.H.$ $V_{IO} = 0, f = 1MHz$	

* Typical values at $T_a = 25^{\circ}C$

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Typical Electro-Optical Characteristics Curves

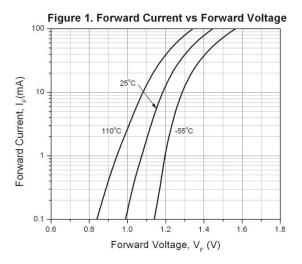


Figure 3. Current Tranfer Ratio vs Ambient Temperature

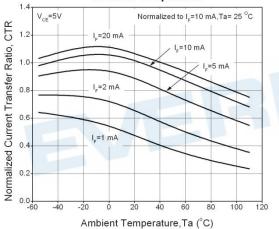
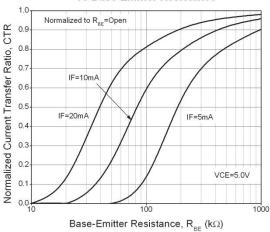


Figure 5. Current Transfer Ratio (Unsaturated) vs Base-Emitter Resistance



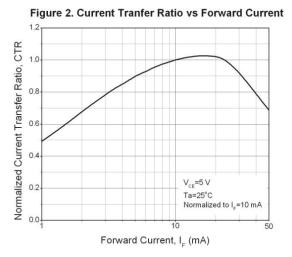
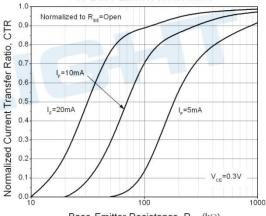
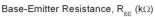
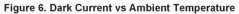
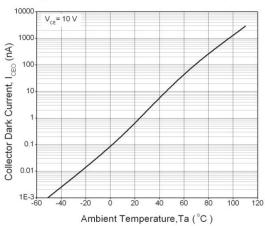


Figure 4. Current Transfer Ratio (Saturated) vs Base-Emitter Resistance









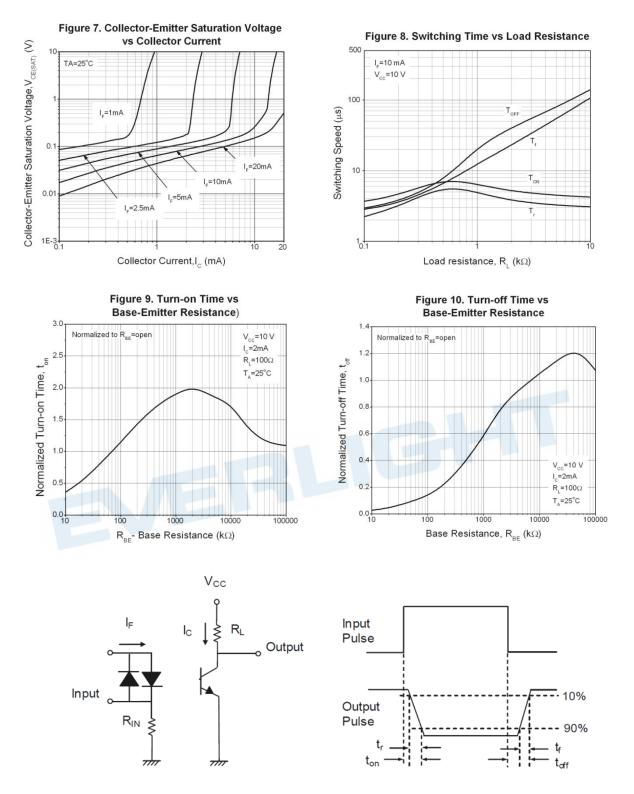


Figure 11. Switching Time Test Circuit & Waveforms

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Order Information

Part Number



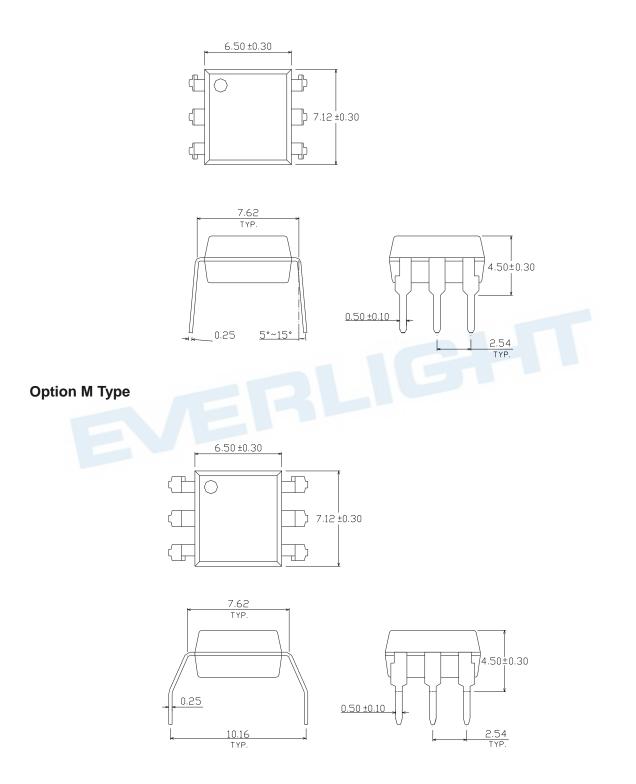
Notes

- Х = CTR Rank (1, 2, 3, or 4)
- Y = Lead form option (S, S1, M or none)
- Z V = Tape and reel option (TA, TB, or none).
- = VDE safety (optional).

Option	Description	Packing quantity
None	Standard DIP-6	65 units per tube
М	Wide lead bend (0.4 inch spacing)	65 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel

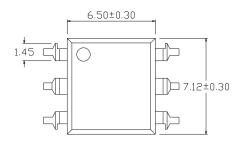
Package Dimension (Dimensions in mm)

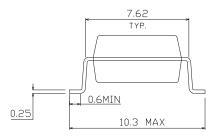
Standard DIP Type

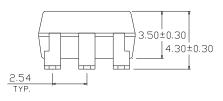


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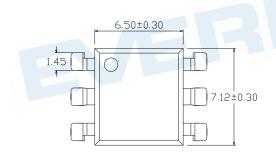
Option S Type

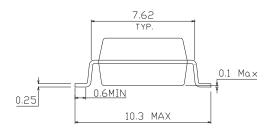


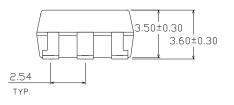




Option S1 Type

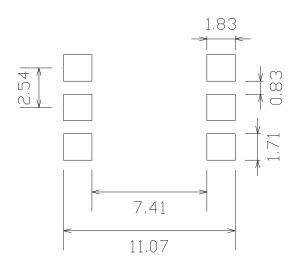








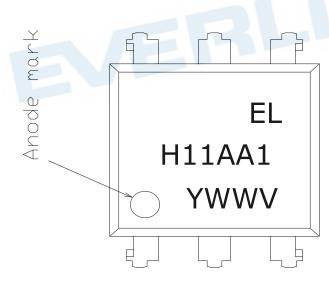
Recommended pad layout for surface mount leadform



Notes

Suggested pad dimension is just for reference only. Please modify the pad dimension based on individual need.

Device Marking

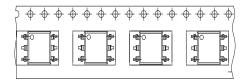


Notes

EL	denotes Everlight
H11AA1	denotes Part Number
Υ	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE safety (optional)

Tape & Reel Packing Specifications

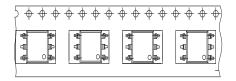
Option TA





Direction of feed from reel

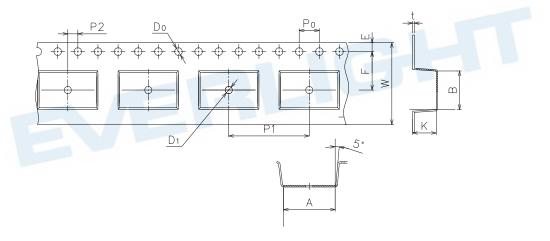
Option TB





Direction of feed from reel

Tape dimensions



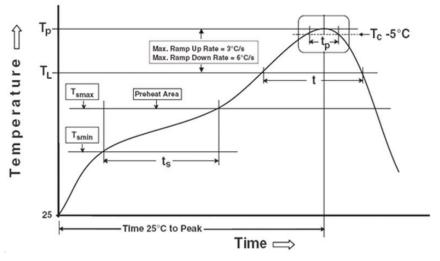
Dimension No.	Α	В	Do	D1	Е	F
Dimension (mm)	10.8±0.1	7.55±0.1	1.5±0.1	1.5+0.1/-0	1.75±0.1	7.5±0.1
Dimension No.	Ро	P1	P2	t	w	к
Dimension (mm)	4.0±0.15	12±0.1	2.0±0.1	0.35±0.03	16.0±0.2	4.5±0.1



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Notes

Preheat

Freneal	
Temperature min (T _{smin})	150 °C
Temperature max (T _{smax})	200°C
Time (T _{smin} to T _{smax}) (t _s)	60-120 seco
Average ramp-up rate $(T_{smax} to T_p)$	3 °C/second

Other

Liquidus Temperature (T_L) Time above Liquidus Temperature (t_L) Peak Temperature (T_P) Time within 5 °C of Actual Peak Temperature: $T_P - 5$ °C Ramp- Down Rate from Peak Temperature Time 25°C to peak temperature Reflow times Reference: IPC/JEDEC J-STD-020D



217 °C 60-100 sec 260°C 30 s 6°C /second max. 8 minutes max. 3 times

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